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FDS4480

40V N-Channel PowerTrench® MOSFET

General Description

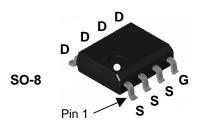
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{\mbox{\scriptsize DS(ON)}}$ and fast switching speed.

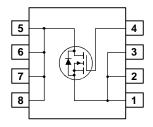
Applications

• DC/DC converter

Features

- 10.8 A, 40 V. $R_{DS(ON)}$ = 12 m Ω @ V_{GS} = 10 V
- Low gate charge (29 nC)
- High performance trench technology for extremely low $R_{\mbox{\scriptsize DS(ON)}}$
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		40	V
V _{GSS}	Gate-Source Voltage		+30/–20	V
I _D	Drain Current - Continuous	(Note 1a)	10.8	А
	– Pulsed		45	
P _D	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.4	
		(Note 1c)	1.2	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +175	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1c)	125	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS4480	FDS4480	13"	12mm	2500 units

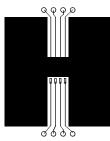
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	ource Avalanche Ratings (Note 2	2)		I	I	I
E _{AS}	Drain-Source Avalanche Energy	Single Pulse, V _{DD} =40V, I _D =10.8A			240	mJ
I _{AS}	Drain-Source Avalanche Current				10.8	Α
Off Char	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \qquad I_{D} = 250 \mu\text{A}$	40			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, Referenced to $25^{\circ}C$		42		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 32 V, V _{GS} = 0 V			1	μΑ
I _{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	racteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2	3.9	5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		-8		mV/°C
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_D = 10.8 \text{ A}$ $V_{GS} = 10 \text{ V}, I_D = 10.8 \text{ A}, T_J = 125^{\circ}\text{C}$		8 13	12 21	mΩ
I _{D(on)}	On-State Drain Current	V _{GS} = 10 V, V _{DS} = 5 V	22			Α
g FS	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_{D} = 10.8 \text{ A}$		36		S
Dynamic	c Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		1686		pF
C _{oss}	Output Capacitance			384		pF
C _{rss}	Reverse Transfer Capacitance			185		pF
Switchir	ng Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time	$\begin{aligned} V_{DD} &= 20 \text{ V}, I_D = 1 \text{ A}, \\ V_{GS} &= 10 \text{ V}, R_{GEN} = 6 \Omega \end{aligned}$		12	22	ns
t _r	Turn-On Rise Time			9	18	ns
t _{d(off)}	Turn-Off Delay Time			30	48	ns
t _f	Turn-Off Fall Time			15	27	ns
Q _g	Total Gate Charge	$V_{DS} = 20 \text{ V}, I_{D} = 10.8 \text{ A}, $ $V_{GS} = 10 \text{ V}$		29	41	nC
Q_{gs}	Gate-Source Charge			8.7		nC
Q_{gd}	Gate-Drain Charge]		8.0		nC

Electrical Characteristics

T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Drain-Source Diode Characteristics and Maximum Ratings							
Is	Maximum Continuous Drain-Source Diode Forward Current				2.1	Α	
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 2.1 \text{ A} \text{(Note 2)}$		0.7	1.2	V	
t _{rr}	Diode Reverse Recovery Time	$I_F = 10.8 \text{ A}, d_{iF}/d_t = 100 \text{ A/}\mu\text{s}$		27		nS	
Q _{rr}	Diode Reverse Recovery Charge			58		nC	

1. R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $\rm R_{\theta JC}$ is guaranteed by design while $\rm R_{\theta CA}$ is determined by the user's board design.



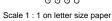
a) 50°C/W when mounted on a 1in² pad of 2 oz copper



b) 105°C/W when mounted on a .04 in² pad of 2 oz copper



c) 125°C/W when mounted on a minimum pad.



2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

Typical Characteristics

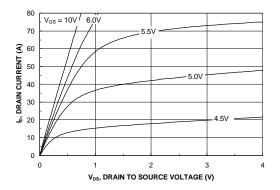


Figure 1. On-Region Characteristics.

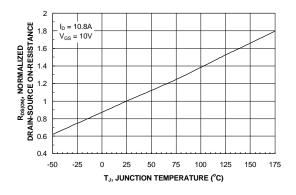


Figure 3. On-Resistance Variation withTemperature.

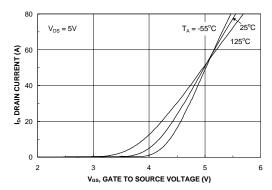


Figure 5. Transfer Characteristics.

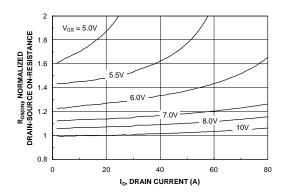


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

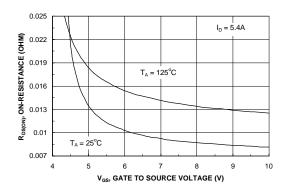


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

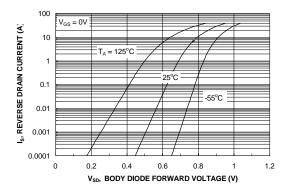
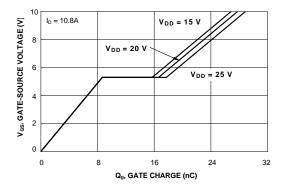


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics



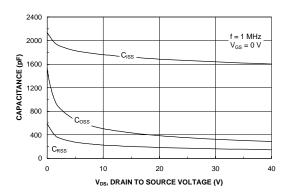
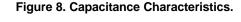
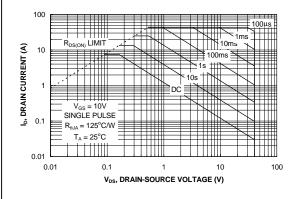


Figure 7. Gate Charge Characteristics.





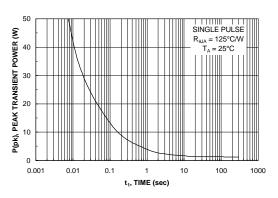


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

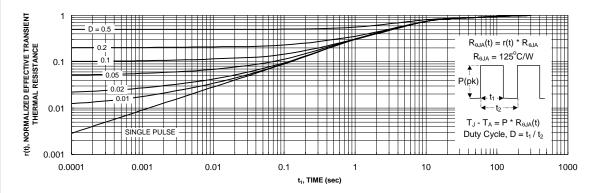


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1c. Transient thermal response will change depending on the circuit board design.

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